


**APPLICATION DATA SHEET**

Electronic Version v14

Stylesheet Version v14.0

<b>Title of Invention</b>	[FLASH MEMORY DEVICE STRUCTURE AND MANUFACTURING METHOD THEREOF]		
<b>Application Type :</b>		regular, utility	
<b>Attorney Docket Number :</b>		10326-US-PA-1	
<b>Correspondence address:</b>			
<b>Customer Number:</b>	31561		
<b>Continuing Data:</b>			
This is a Division of US application number 10249362, filed 2004-04-03 , now pending.			
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<b>Inventors Information:</b>			
<u>Inventor 1:</u>			
<b>Applicant Authority Type:</b>	Inventor		
<b>Citizenship:</b>	TW		
<b>Name prefix:</b>	Mr.		
<b>Given Name:</b>	Chih-Wei		
<b>Family Name:</b>	Hung		
<b>Residence:</b>			
<b>City of Residence:</b>	Hsin-chu City		
<b>Country of Residence:</b>	TW		
<b>Address-1 of Mailing Address:</b>	7F-3, No. 106, St. Hwai-yuan,		
<b>Address-2 of Mailing Address:</b>			
<b>City of Mailing Address:</b>	Hsin-chu City		
<b>State of Mailing Address:</b>			
<b>Postal Code of Mailing Address:</b>			
<b>Country of Mailing Address:</b>	TW		
<b>Phone:</b>			
<b>Fax:</b>			
<b>E-mail:</b>			

Inventor 2:

**Applicant Authority Type:** Inventor  
**Citizenship:** TW  
**Name prefix:** Mr.  
**Given Name:** Min-San  
**Family Name:** Huang  
**Residence:**  
**City of Residence:** Hsinchu  
**Country of Residence:** TW  
**Address-1 of Mailing Address:** No. 7, Po-Chuan San Rd.,  
**Address-2 of Mailing Address:**  
**City of Mailing Address:** Hsinchu  
**State of Mailing Address:**  
**Postal Code of Mailing Address:**  
**Country of Mailing Address:** TW  
**Phone:**  
**Fax:**  
**E-mail:**

**Attorney Information:**

practitioner(s) at Customer Number:

31561



as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.